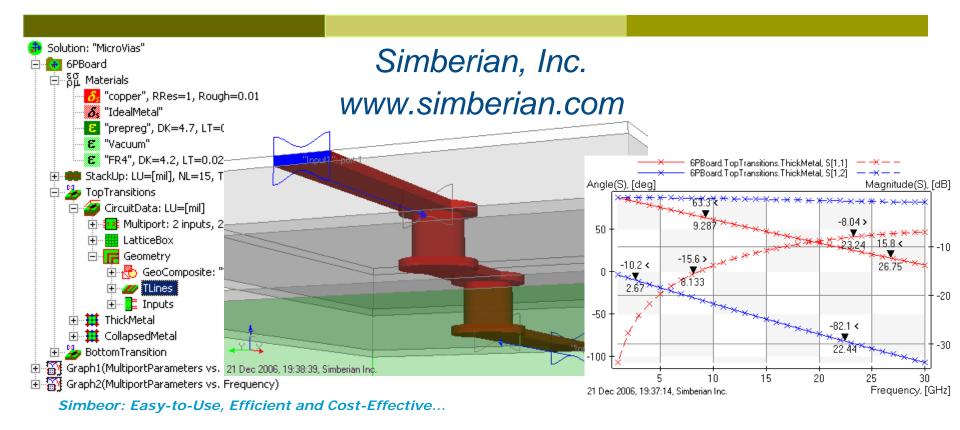


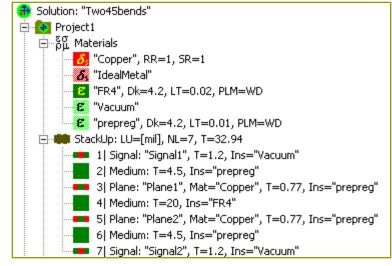
Comparison of S-parameters of 90-deg. with two 45-deg. bends in microstrip line



StackUp

StackUp from Tutorial 1





2



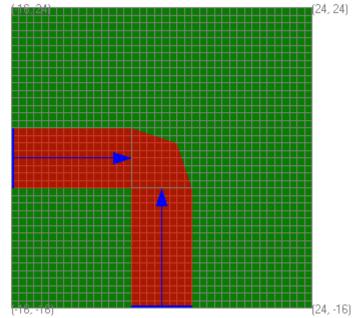
10/7/2008 © 2007 Simberian Inc.

Circuit Bend0

90-degree bend in 8-mil microstrip line in layer "Signal1", bend is slightly rounded-off

> Grid: 40 by 40, dx=1, dy=1, 1 level SuperGrid: ProgressiveGrid, max 9dx by 9dy Symmetry: Diagonal Plane Reflection Analysis: Multiport, Lossy Matrix: 340 by 340, Allocated

Circuit Bend0, Parameter dist=0 mil



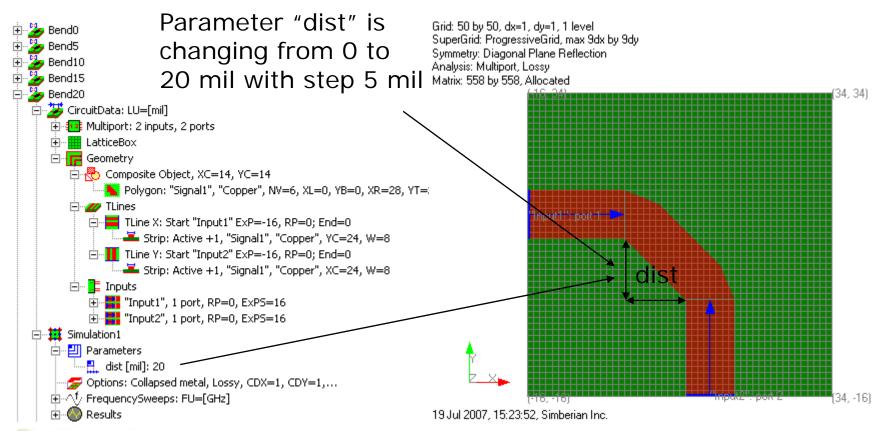
19 Jul 2007, 15:15:48, Simberian Inc.

10/7/2008

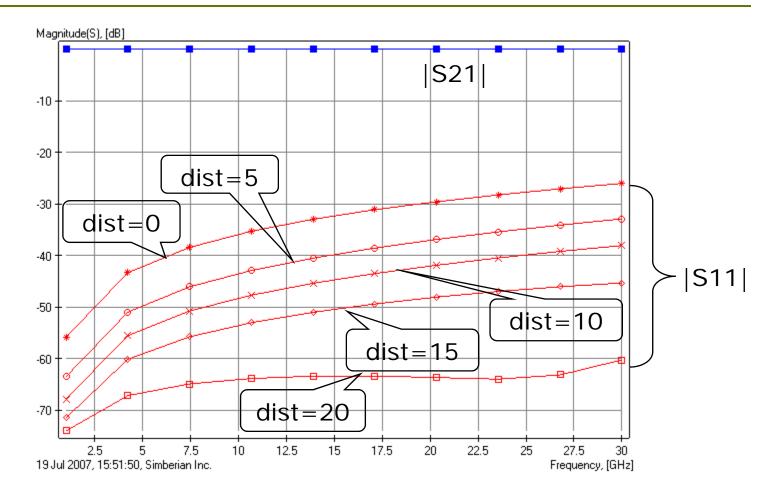


Circuits Bend5-Bend20

Two 45-degree bends in 8-mil microstrip line in layer "Signal1"



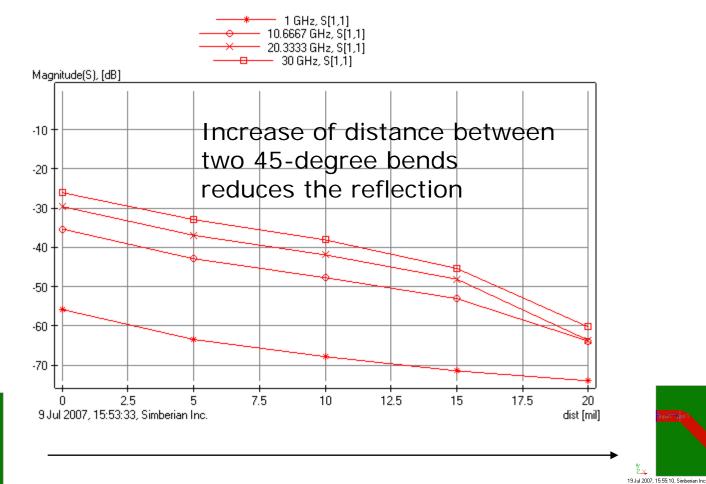
S-parameters vs. frequency





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|S11| vs. parameter "dist"





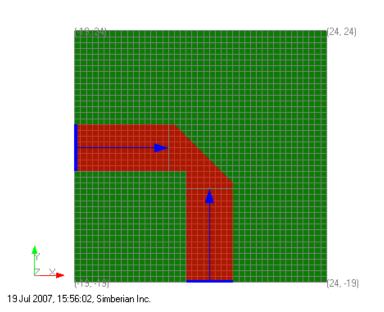
19 Jul 2007, 15:54:24, Simberian Inc.

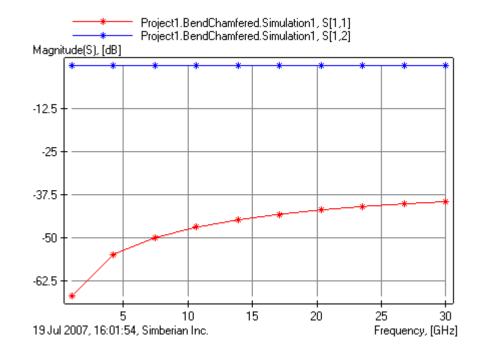
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Chamfered bend

Smaller footprint almost the same performance as two widely spaced 45-degree bends





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Conclusion

- Reflection coefficients are very small for all investigated configurations – the effect may be not even visible on TDR
- Discontinuity effect comes mostly from the excessive capacitance of the bend
- Two 45-degree bends are better than nonchamfered 90-degree bend
- Chamfered 90-degree bend is a good alternative and is comparable with two widely spaced 45degree bends



Solution and contact

- Solution Two45Bends.esx and project files, used to illustrate these notes, are available after installation of Simbeor 2007 in My Documents / Simbeor Solutions / PCB_MCM / Two45Bends
- Send questions and comments to
 - General: info@simberian.com
 - Sales: sales@simberian.com
 - Support: <u>support@simberian.com</u>
- Web site <u>www.simberian.com</u>

